MICRO-566



# Large-area electronics: devices and materials

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Cursus	Sem.	Туре	Language of	English
Energy Management and Sustainability	MA2, MA4	Opt.	teaching	Linglish
Microtechnics	MA2, MA4	Opt.	Credits	3
	,		Session	Summer
			Semester	Spring
			Exam	Oral
			Workload	90h
			Weeks	14
			Hours	3 weekly
			Courses	2 weekly
			Exercises	1 weekly
			Number of	
			positions	

### Summary

Introduction to the physical concepts involved in the description of optical and electronic transport properties of thin-film semiconductor materials found in many large-area applications (solar cells, displays, imagers, etc) and introduction to the physics of the related devices.

### Content

This lecture will start with the general description of thin-film materials which are common in macro-electronic applications. These materials include metal oxides, disordered semiconductors and organic materials. The effect of disorder at the atomic scale on electronic states and electronic transport properties will be discussed, as well as the optical characteristics of such materials in relation to device applications. Then the device physics of various devices based on disordered semiconductors will be presented: first solar cells will be discussed and especially the relation between the material properties (absorption behavior and charge transport) on the cell efficiency. Finally other examples of large-area devices such as photo-detectors, particle sensors and Thin-Film Transistors (for flat panel displays and flat panel imagers) will be presented; the physics of these devices and some fabrication aspects will also been discussed.

### **Keywords**

- thin-films
- ordered and disordered semiconductors
- transparent conductive metal oxides
- organic semiconductors
- optical properties
- electronic properties
- solar cells
- transistors
- particle sensors

### **Learning Prerequisites**

Required courses Semiconductor physics or Solid State Physics

**Learning Outcomes** 

By the end of the course, the student must be able to:

- Distinguish ordered and disordered semiconductors.
- Classify order in a solid on short, medium, and long range.
- Visualize the properties of shallow and deep states in a semiconductor.
- Predict charge transport in semiconductors with band-tails.
- Predict recombination of charge carriers at deep defect states.
- Sketch the working principle of solar cells with p-n and p-i-n junction.
- Sketch the operation of thin film transistors.
- Model the function of thin film transistors in displays, imagers, etc.

### **Assessment methods**

Oral examination

# Resources

**Bibliography** Arvind Shah, Thin-film silicon solar cells, EPFL Press, 2010. Robert Street, Hydrogenated amorphous silicon, Cambridge University Press

#### Ressources en bibliothèque

- Hydrogenated amorphous silicon / Street
- Thin-film silicon solar cells / Shah